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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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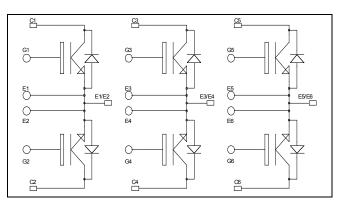






Triple dual Common Source NPT IGBT Power Module

 $V_{CES} = 1200V$ $I_{C} = 50A$ @ Tc = 80°C



Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Non Punch Through (NPT) FAST IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a dual common source configuration of three times the current capability
- RoHS compliant

Absolute maximum ratings

® E2 ® G2

Absolute maximum ratings							
Symbol	Parameter		Max ratings	Unit			
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V			
I_{C}	Continuous Collector Current	$T_c = 25^{\circ}C$	75				
	Continuous Conector Current	$T_c = 80$ °C	50	A			
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	150				
$ m V_{GE}$	Gate – Emitter Voltage		±20	V			
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	312	W			
RBSOA	Reverse Bias Safe Operating Area	$T_{j} = 150^{\circ}C$	100A @ 1200V				

E5/E6

€6€

® E4 ® G4

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
T	Zara Cata Valtaga Callactar Current	$V_{GE} = 0V$	$T_i = 25^{\circ}C$			250	4
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 1200V$	$T_{i} = 125^{\circ}C$			500	μΑ
* 7	C. II. day Farittan and anti-m Walkers	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		3.2	3.7	V
$V_{CE(sat)}$	Collector Emitter saturation Voltage	$I_C = 50A$	$T_j = 125$ °C		4.0		V
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1 \text{ mA}$		4.5		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20 \text{ V}, V_{CE} = 0 \text{ V}$				100	nA

Dynamic Characteristics

·	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			3450		pF
C_{oes}	Output Capacitance				330		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			220		
Q_{g}	Total gate Charge	$V_{GS} = 15V$			330		
Q_{ge}	Gate – Emitter Charge	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 50A$			35		nC
Q_{gc}	Gate – Collector Charge				200		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 50A$ $R_{G} = 5 \Omega$			35		ns
T_{r}	Rise Time				65		
$T_{d(off)}$	Turn-off Delay Time				320		
T_{f}	Fall Time				30		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 50A$ $R_{G} = 5 \Omega$			35		ns
$T_{\rm r}$	Rise Time				65		
$T_{d(off)}$	Turn-off Delay Time				360		
$T_{\rm f}$	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		6.9		I ma I
E_{off}	Turn-off Switching Energy	$I_{C} = 50A$ $R_{G} = 5 \Omega$	$T_j = 125$ °C		3.05		mJ

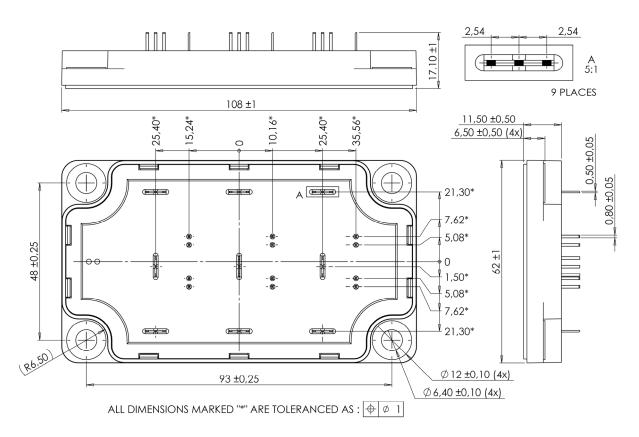
Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$			250 500	μА
I_{F}	DC Forward Current		$Tc = 70^{\circ}C$		60		A
	Diode Forward Voltage	$I_F = 60A$			2.0	2.5	V
V_{F}		$I_{\rm F} = 120A$			2.3		
		$I_F = 60A$	$T_{j} = 125^{\circ}C$		1.8		
t _{rr}	Reverse Recovery Time	$ \begin{array}{c c} I_F = 60A & T_j = 25^{\circ}C \\ V_R = 800V & T_j = 125^{\circ}C \\ di/dt = 200A/\mu s & T_j = 25^{\circ}C \\ \hline T_j = 125^{\circ}C & \\ T_j = 125^{\circ}C & \\ \end{array} $	$T_j = 25$ °C		400		
			$T_{\rm j} = 125^{\circ}{\rm C}$		470		ns
Q _{rr}	Reverse Recovery Charge		$T_j = 25$ °C		1200		nC
				4000		nC	

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.4	°C/W
			Diode			0.9	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight					250	g

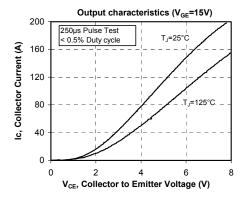
SP6-P Package outline (dimensions in mm)

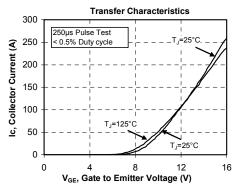


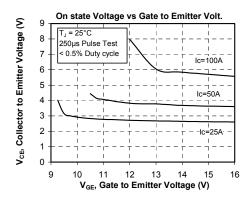
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

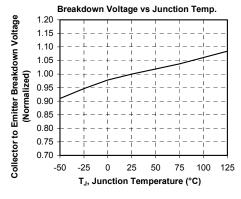


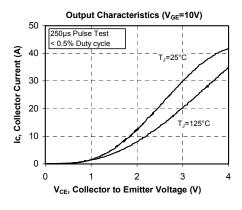
Typical Performance Curve

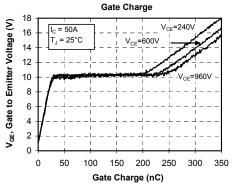


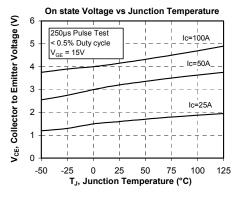


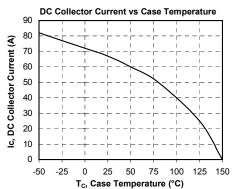




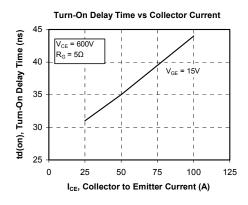


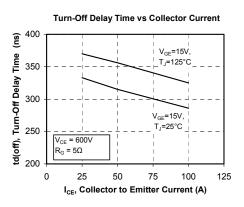


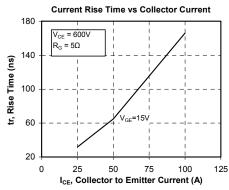


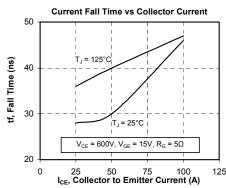


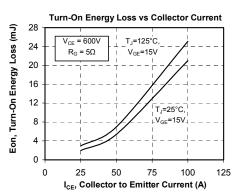


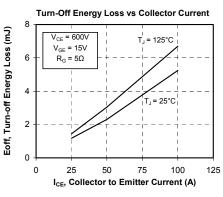


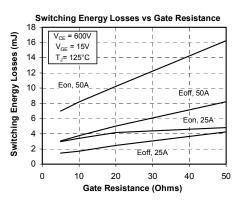


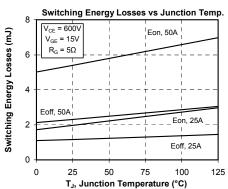




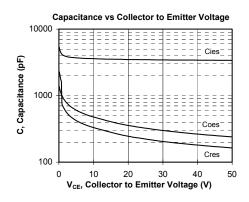


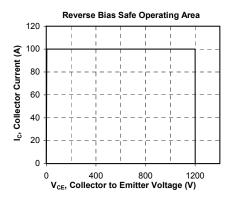


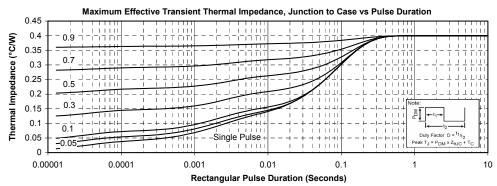


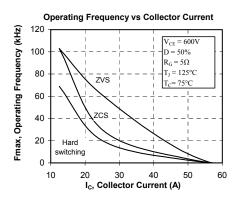












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